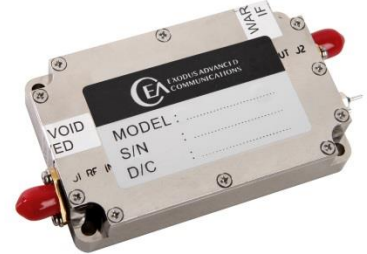




AMP1114 SOLID STATE HIGH POWER AMPLIFIER

FEATURES

- Class AB linear GaN design
- Instantaneous wide bandwidth
- Suitable for all modulations standards
- Built-in protection circuits
- High reliability and ruggedness



ELECTRICAL SPECIFICATIONS

Parameter	Specification	Notes
Operating Frequency Range	100 - 2000MHz	
Power Output Psat	2 Watt Min	CW
Power Gain	33 dB Min	
Power Gain Flatness	3.0 dB p-p Max	
Input Return Loss	10 dB Min	Relative to 50 Ohm
2-Tone Intermodulation (IMD)	>30 dBc	23dBm/Tone, Δ = 1MHz
Harmonics 2 nd / 3rd	>15 dBc Typ	At rated Pout
Non Harmonics Spurious	>60 dBc	
Operating Voltage	28 VDC Nom	
Current Consumption	1 Amp Max	At rated Pout
Max Input Power	+8 dBm Max	Without damage
Load VSWR Protection	∞ : 1	

ENVIRONMENTAL CHARACTERISTICS

Parameter	Specification	Notes
Operating Case Temperature	-20 to +65 °C	
Storage Temperature	-40 to +85 °C	
Relative Humidity	5 to 95 %	Non Condensation

MECHANICAL SPECIFICATIONS

Parameter	Specification	Notes
Dimensions	80 x 60x 27mm	Without Connectors
Weight	150 gr.	Max Weight
RF Connectors In/Out	SMA female	
DC Power / Interface Connector	Feed Thru	
Cooling	External Heatsink	

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OUTLINE DRAWING

